Intermediate Valence Model for Tl$_2$Mn$_2$O$_7$

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There have been speculations about the need to find a new mechanism to explain the colossal magnetoresistance exhibited by this material, having pyrochlore structure and thus differing structurally and electronically from the manganites. We will report here our transport results based on a two band model, with conduction electrons and intermediate valence ions fluctuating between two magnetic configurations. The model has been previously employed to understand transport and thermodynamical properties of intermediate valence Tm compounds and, in its periodic version, to analyze the phase diagram. The results obtained with this model for the transport properties of Tl$_2$Mn$_2$O$_7$ are in good qualitative agreement with the experimental results.

The strong correlation between transport properties and magnetism in perovskite manganese oxides like La$_{1-x}$M$_x$MnO$_3$ (M=Ca,Sr,Ba) has been known for many years [1]. Shortly after the discovery of these materials, the double exchange mechanism was proposed [2] to describe the interactions between the Mn ions which, due to the divalent substitution for La, are in a mixed valence state. Electronic carrier hopping between heterovalent Mn pairs (Mn$^{3+}$-Mn$^{4+}$) is enhanced by the mutual alignment of the two magnetic moments. Thus the resistivity will depend on the spin disorder and is expected to display pronounced features at the ferromagnetic ordering temperature ($T_c$). On application of a magnetic field, which tends to align the local spins, the resistivity is expected to decrease.

Recently, colossal magnetoresistance (denoted MR hereafter) was observed near the ferromagnetic ordering temperature [3] and the interest in the study of these materials was renewed. At present, there is disagreement on whether theoretical models based only on the double exchange mechanism can account quantitatively for the observed transport and magnetic properties of the manganese perovskites. It has been proposed that other ingredients such as disorder [1], Jahn Teller distortions [3], etc. should be included and would play an important role.

In 1996 colossal magnetoresistance was observed for the non-perovskite Tl$_2$Mn$_2$O$_7$ compound [3,8]. This material has the pyrochlore $A_2B_2O_7$ structure [9], consisting of AO$_8$ cubes and BO$_6$ octahedra linked to form a three-dimensional network of corner-sharing tetrahedra. This tetrahedral MnO$_6$ (B=Mn) network differentiates the pyrochlores from the perovskite ABO$_3$ structure, with a cubic MnO$_2$ network. The pyrochlore structure is face-centered cubic with 8 formula units per unit cell. Tl$_2$Mn$_2$O$_7$ undergoes a ferromagnetic transition with $T_c \sim 140$ K [3,8]. Below $T_c$ the compound is ferromagnetic, whereas above $T_c$ it is paramagnetic. The magnetoresistance maximum around the ferromagnetic ordering temperature is similar to that obtained for the manganese perovskites. Mostly due to the absence of evidence for significant doping in the pyrochlore Mn-O sublattice (to produce the mixed valence responsible for double exchange in perovskite manganese oxides about 20-45% doping is needed), and due to the tendency of Tl to form 6-s conduction bands (unlike the perovskites where the rare-earth levels are electronically inactive), it has been put to question whether a double exchange mechanism similar to that of perovskites can account for the experimental results [3,8]. Hall data [3] show a very small number of n-type carriers ($\sim 0.005$ conduction electrons per formula unit) and this would seem to indicate a very small doping into the Mn$^{4+}$ state [3,8]. Among possible explanations, the authors of Refs.[6,8] mention that such Hall data could result from a small number of carriers in the TI 6-s band, so that assuming Tl$^{3+}$-Tl$^{4+}$Mn$^{4+}$-Mn$^{5+}$O$_7$ with $x \sim 0.005$ the data could be accounted for.

Based on these facts we decided to explore the suitability of the intermediate valence (IV) model now to be introduced for Tl$_2$Mn$_2$O$_7$. The model was proposed originally for the study of Tm compounds [10,11]. The exactly solvable impurity model for valence fluctuations between two magnetic configurations was shown [11] to describe most of the peculiar features of the magnetic properties of paramagnetic intermediate valence Tm compounds. The impurity model resistivity exhibits an explicit quadratic dependence with the magnetization [11]. Such a behaviour has also been found in transport experiments slightly above $T_c$ for colossal MR pyrochlores [3] and manganese perovskites [2]. With the periodic array of IV ions version of the model [11] the effect of the interactions between Tm ions was studied, obtaining the T=0 phase diagram, specific heat and magnetic susceptibility for the paramagnetic phase in coherent potential approximation (CPA) and the neutron scattering spectrum. For manganese perovskites a similar model has been considered [12] to propose the possibility of a metal-insulator transition.

We will now present the model employed to describe a periodic lattice of intermediate valence (IV) ions, which fluctuate between two magnetic configurations associated to single (S=1/2) or double occupation (S=1) of the ion, hybridized to a band of conduction states. The hamilo-
The IV ions, which for Tl$_2$Mn$_2$O$_7$ we would identify with the Mn ions, are represented by $H_L$, which describes the S=1/2 magnetic configuration at site $j$ through states $\ket{j \sigma}$ ($\sigma = \uparrow, \downarrow$), with energies $E_s$, split in the presence of a magnetic field $B$ according to:

$$E_{s(1)} = E - (\pm)\mu_0 B.$$  \hspace{1cm} (2)

$H_c$ describes the conduction band, which for Tl$_2$Mn$_2$O$_7$ we would identify with the Tl $6s$ conduction band. Through hybridization with the conduction band, $H_H$ describes valence fluctuations between the two magnetic configurations at one site. For example, through promotion of a spin up electron into the conduction band at site $j$ the IV ion passes from state $\ket{j \uparrow}$ to state $\ket{j \downarrow}$. Notice that the highly anisotropic limit considered inhibits any spin flip scattering of conduction electrons, so that the direction of the local spin at each site is conserved. IV ions only hybridize with conduction electrons of parallel spin.

The hamiltonian can be rewritten in terms of the following creation (and related annihilation) operators for the local orbitals (Mn 3-d orbitals, in this case) $[11]$:

$$d_{j,\uparrow}^+ = \ket{j \uparrow},$$

$$d_{j,\downarrow}^+ = \ket{j \downarrow},$$  \hspace{1cm} (4)

for which one has:

$$[d_{i,\uparrow}, d_{j,\uparrow}^+] = \delta_{i,j} (P_{\uparrow} + P_{\downarrow}),$$

$$[d_{i,\downarrow}, d_{j,\uparrow}^+] = \delta_{i,j} (P_{\uparrow} + P_{\downarrow}),$$

$$P_{\uparrow} + P_{\downarrow} + P_{\downarrow} + P_{\downarrow} = 1.$$  

where: $P_{\uparrow,\downarrow} = | j \sigma > < j \sigma |$ are projection operators onto the local magnetic configuration states. The local hamiltonian now reads:

$$H_L = (\Delta - \mu DB) \sum_j d_{j,\downarrow}^+ d_{j,\uparrow} + (\Delta + \mu DB) \sum_j d_{j,\uparrow}^+ d_{j,\downarrow},$$

$$\mu_D = \mu_1 - \mu_0.$$  \hspace{1cm} (5)

Due to the type of hybridization present, one can now consider the problem as described by two separate parts $[11]$. Given a certain configuration for the occupation of the local orbitals at all sites with spin up or down electrons, the spin up conduction electrons will only hybridize with those IV ions occupied by spin up electrons (i.e. in $\uparrow$ or + local states). One could simulate this by including a very high local correlation energy ($U \to \infty$) to be paid in the event of mixing with ions occupied by opposite spin electrons. Concretely, we can take $[11]$:

$$H = H_\uparrow + H_\downarrow,$$  \hspace{1cm} (6)

$$H_\uparrow = (\Delta - \mu DB) \sum_{j \in \uparrow} d_{j,\downarrow}^+ d_{j,\uparrow} + U \sum_{j,k} d_{j,\uparrow}^+ d_{j,\uparrow} + \sum_{k} \epsilon_k c_{k,\uparrow}^+ c_{k,\uparrow} + \sum_{i,j} \left(V_{i,j} d_{j,\downarrow}^+ c_{i,\uparrow} + H.c. \right).$$

$H_\downarrow$ is analogous to $H_\uparrow$, one having only to reverse the sign of $B$ and spin directions. We will ignore the split of the conduction band energies in the presence of the magnetic field $B$, and take for the hybridization: $V_{i,j} = \delta_{i,j}$.

Given a certain configuration of up and down spin occupations of the sites, one can now solve two separate alloy problems, described by $H_\uparrow$ and $H_\downarrow$ respectively. These we solved in CPA approximation as in Ref. $[11]$, introducing an effective diagonal self-energy for the local orbitals, $\Sigma_{d(\sigma)}(\omega)$ for the $H_\sigma$ alloy problem, through which an average translational symmetry is restored. The CPA equation obtained to determine self-consistently the self-energy relates it directly to the local Green function for the IV ions:

$$\Sigma_{d(\uparrow)}(\omega) = \frac{p-1}{<< d_{j,\downarrow}^+ d_{j,\uparrow}^+ >> (\omega)},$$

$$\Sigma_{d(\downarrow)}(\omega) = \frac{-p}{<< d_{j,\downarrow}^+ d_{j,\downarrow}^+ >> (\omega)}. \hspace{1cm} (7)$$

Here $p$ denotes the concentration of spin up sites, and for the densities of states hold:

$$\int_{-\infty}^{\infty} d\omega \rho_{d,\sigma}(\omega) = 1,$$

$$\int_{-\infty}^{\infty} d\omega \rho_{d,\downarrow}(\omega) = p, \int_{-\infty}^{\infty} d\omega \rho_{d,\uparrow}(\omega) = 1 - p. \hspace{1cm} (8)$$

The CPA equation is solved self-consistently with the total number of particles equation, through which the chemical potential is determined.
To take into account the effect of temperature on the magnetization and describe qualitatively the experimental data in pyrochlores \[14\], we will use a simple Weiss molecular field approximation to obtain the magnetization at each temperature \[14\] and through this the concentration \( p \) of ions occupied by spin up electrons.

Considering now the determination of transport properties, using the Kubo formula it has been proved before \[13,16\] that no vertex corrections to the conductivity are obtained in a model such as this. Furthermore, in the absence of a direct hopping term between local orbitals only the conduction band at the origin, \( \mu \), is related to the effective medium CPA self-energy \( \Sigma \) obtained at \( T=0 \) with those parameters. At temperature, one can approximate: \( \Phi(\omega) \sim v_F^2 \rho_c^0(\omega) \), being \( v_F \) the Fermi velocity. The results presented here were obtained assuming for simplicity a semielliptic bare conduction half-bandwidth (centering the conduction band at the origin), \( E = 0 \), \( \Delta = -4.8 \) eV, \( V = 0.6 \) eV and total number of particles per site \( n = 1.075 \). To reproduce qualitatively the experimental magnetization data \[15,16\] we take \( T_c \) as 142K and a saturation value of \( 3\mu_B \) (like for free \( \text{Mn}^{4+} \) ions) in the Weiss approximation, as well as \( \mu_D = 1\mu_B \). In Fig.7 we show the gap in the CPA spin up densities of states obtained at \( T_c=0 \) with those parameters. At temperatures above \( T_c \) there still are gaps present (or at least pseudogaps, as is the case for the spin down bands at the higher magnetic fields shown: \( B=4T, 8T \)). A filling of \( n=1.075 \) corresponds to the Fermi level placed slightly above the bottom of the upper bands (\( \mu \sim -4.51 \) eV). The resistivity curves in Fig.8 have a behaviour around \( T_c \) similar to that found in experiments \[16\]. An order of magnitude estimate for our resistivity results for \( n=1.075 \) is compatible with the values experimentally found (see Fig.8), in any case the absolute value of resistivity we obtain depends on the filling. In Fig.8 we plot magnetoresistance results obtained with the same parameters. Here our results exhibit a difference in value between the MR maxima around \( T_c \) for different magnetic fields and a crossing at higher temperatures of the MR curves obtained for those \( B \), such as are present in the experimental data \[8\]. The description of the main features exhibited by transport measurements around \( T_c \) is quite remarkable, considering the simplifications adopted here. Moreover, with the parameters employed (and due to the resulting presence of gaps or pseudogaps slightly below the Fermi level) we have a small effective number of electrons participating in the transport (mostly the few Ti conduction electrons above the gap) like Hall experiments indicate \[15,16\]. Nevertheless it is the total number of conduction electrons (which includes those below the gap and with our parameters is about 0.15, ten times the number of carriers above the gap) which would represent the real doping (\( x \)) into the \( \text{Mn}^{4+} \) state to take into consideration. This could solve the difficulties with Hall data which are mentioned in Refs. \[15,16\].

We will now briefly comment on the transport results obtained with the impurity version of the model discussed above \[14\]. Using parameters for the impurity in accordance with those employed for the lattice, and a filling such that the Fermi level falls slightly above the peak of the impurity density of states, one can obtain transport results which are very similar to those presented above. Nevertheless, it would be hard to reconcile the impurity picture with the Hall data indicating a very small number of carriers effective in transport \[15,16\].

To conclude we will indicate that the agreement between our results and the experimental data available on colossal MR pyrochlore \( \text{Tl}_2\text{Mn}_2\text{O}_7 \) is indeed very reasonable, and we believe that it can certainly be improved by fine tuning of the parameters of the model. The presence of gaps or pseudogaps in the electronic structure, such as those considered here in the periodic model, not only could solve the problems posed by the Hall data which are mentioned by the authors of Refs. \[14,16\]. But their presence should cause observable effects in other experiments, such as spin polarized tunneling and optical properties which would be interesting to investigate.
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**Figure Captions:**

**FIG. 1.** Periodic IV model. Resistivity as a function of temperature for magnetic fields: $B=0, 1, 4$ and $8$ T. Parameters: $W=6$ eV, $E=0$, $\Delta = -4.8$ eV, $V=0.6$ eV, $n = 1.075$, $T_c = 142$ K, $M_{sat} = 3\mu_B$, $\mu_D = 1 \mu_B$, $c = \frac{(eV)^2}{n_e e^2 v_F^2 \hbar}$, e.g. $c \sim 0.1 \Omega cm$ for $n_e \sim 10^{21} / cm^3$ and $v_F \sim 10^7 cm/s$.

**FIG. 2.** Periodic IV model. Densities of states as a function of energy at $T=0$, $B=1$ T, parameters as in Fig. (1).
Fig. (1)

- $n=1.075, B=0$
- $B=1T$
- $B=4T$
- $B=8T$
Fig. (2)

Density of states [1/eV]

Energy [eV]

c-up

c-dn

d-up
Magnetoresistance vs Temperature [K]

Fig. (3)